

EF8A05 THRU EF8A60

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EF8A05 THRU EF8A60

8.0A Glass Passivated Efficiency Fast Rectifiers-50-600V

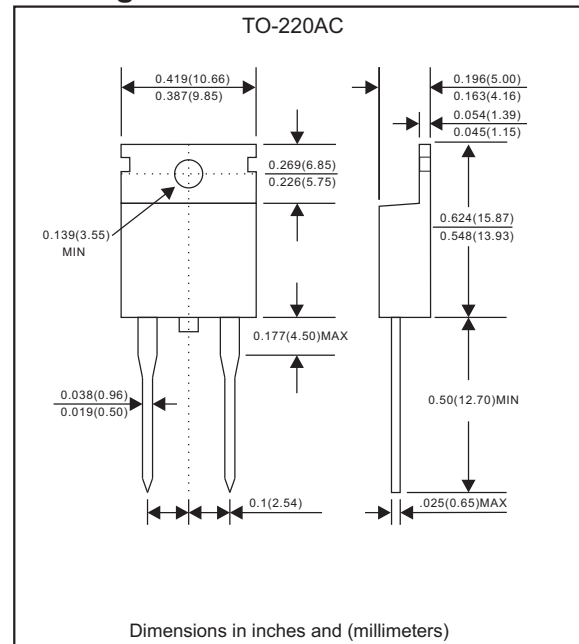
Features

- Reverse recovery time less than 25ns
- High current capability.
- Low reverse leakage current.
- High surge capability.
- Glass passivated chip junction.
- Low forward drop down voltage.
- High reliability.
- Lead-free parts meet RoHS requirements.
- Suffix "-H" indicates Halogen free parts, ex. EF8A05-H.

Mechanical data

- Epoxy : UL94-V0 rated flame retardant
- Case : JEDEC TO-220AC molded plastic body over passivated chip
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity: As marked
- Mounting Position : Any
- Weight : Approximated 2.05 gram

Package outline



Maximum ratings (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOLS	EF8A05	EF8A10	EF8A20	EF8A40	EF8A60	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	V
Maximum average forward rectified current	I_o	8.0					A
Peak forward surge current 8.3ms single half sine-wave (JEDEC method)	I_{FSM}	100					A
Typical diode junction capacitance (Note 1)	C_J	50					pF
Operating junction temperature range	T_J	-55 to +150					$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-65 to +175					$^{\circ}\text{C}$

Electrical characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOLS	EF8A05	EF8A10	EF8A20	EF8A40	EF8A60	UNIT
Maximum forward voltage at $I_F=8.0\text{A}$	V_F	0.98			1.30	1.75	V
Maximum DC reverse current at rated DC blocking voltage	I_R	5.0 200					μA μA
Maximum reverse recovery time (Note 2)	t_{rr}	25					ns

Thermal characteristics

PARAMETER	SYMBOLS	EF8A05	EF8A10	EF8A20	EF8A40	EF8A60	UNIT
Typical thermal resistance junction to case	$R_{\theta JC}$	2.0					$^{\circ}\text{C/W}$

Note 1: Measure at 1 MHz and applied reverse voltage of 4.0 V D.C.

Note 2: Reverse recovery time test condition, $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $IRR=0.25\text{A}$

Rating and characteristic curves (EF8A05 THRU EF8A60)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

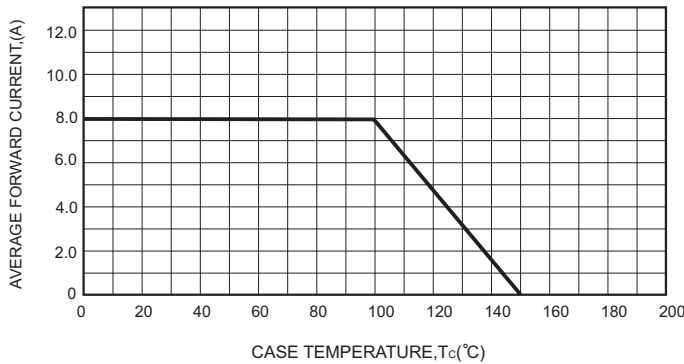


FIG.2-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

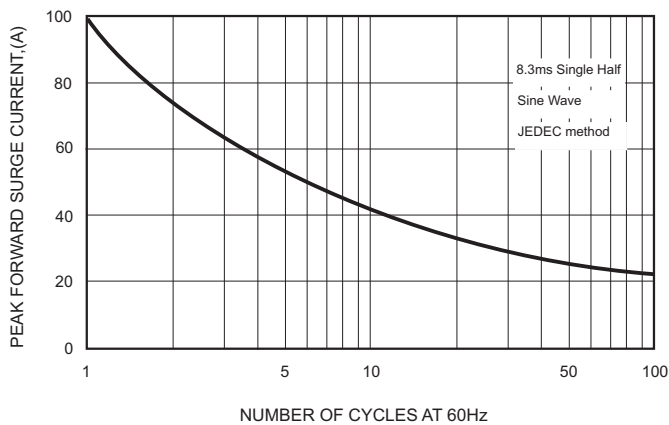


FIG.5- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS

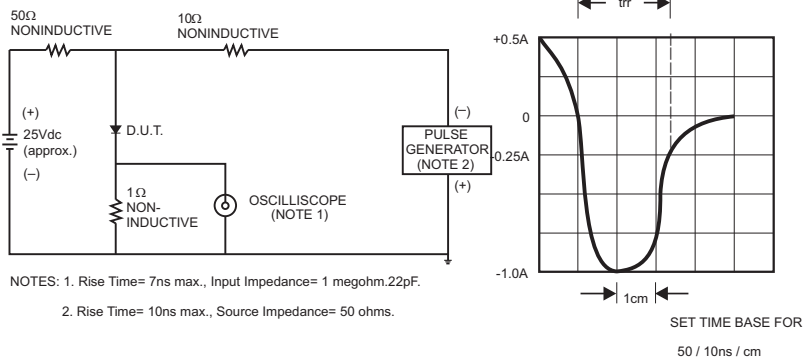


FIG.3-TYPICAL FORWARD

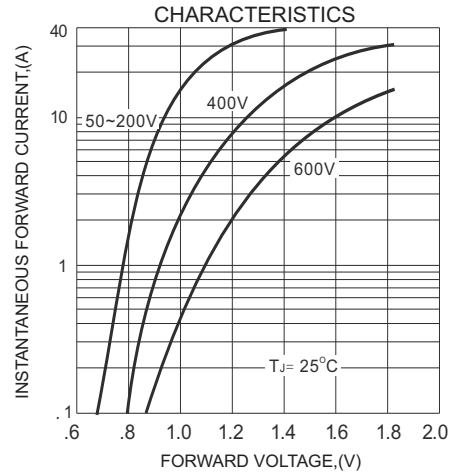
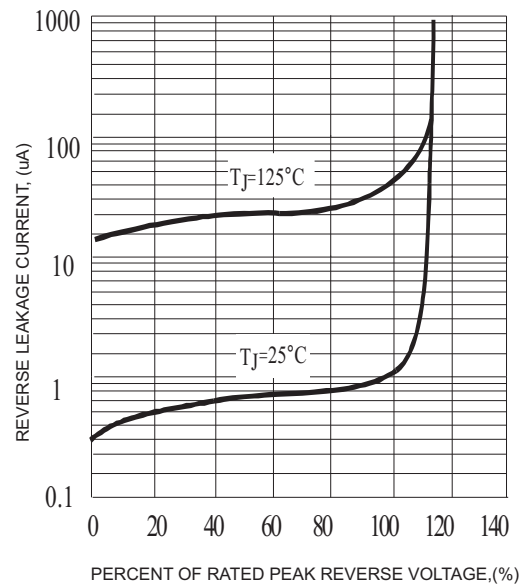
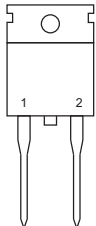
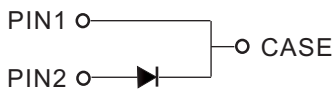


FIG.4 - TYPICAL REVERSE CHARACTERISTICS



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Pinning information

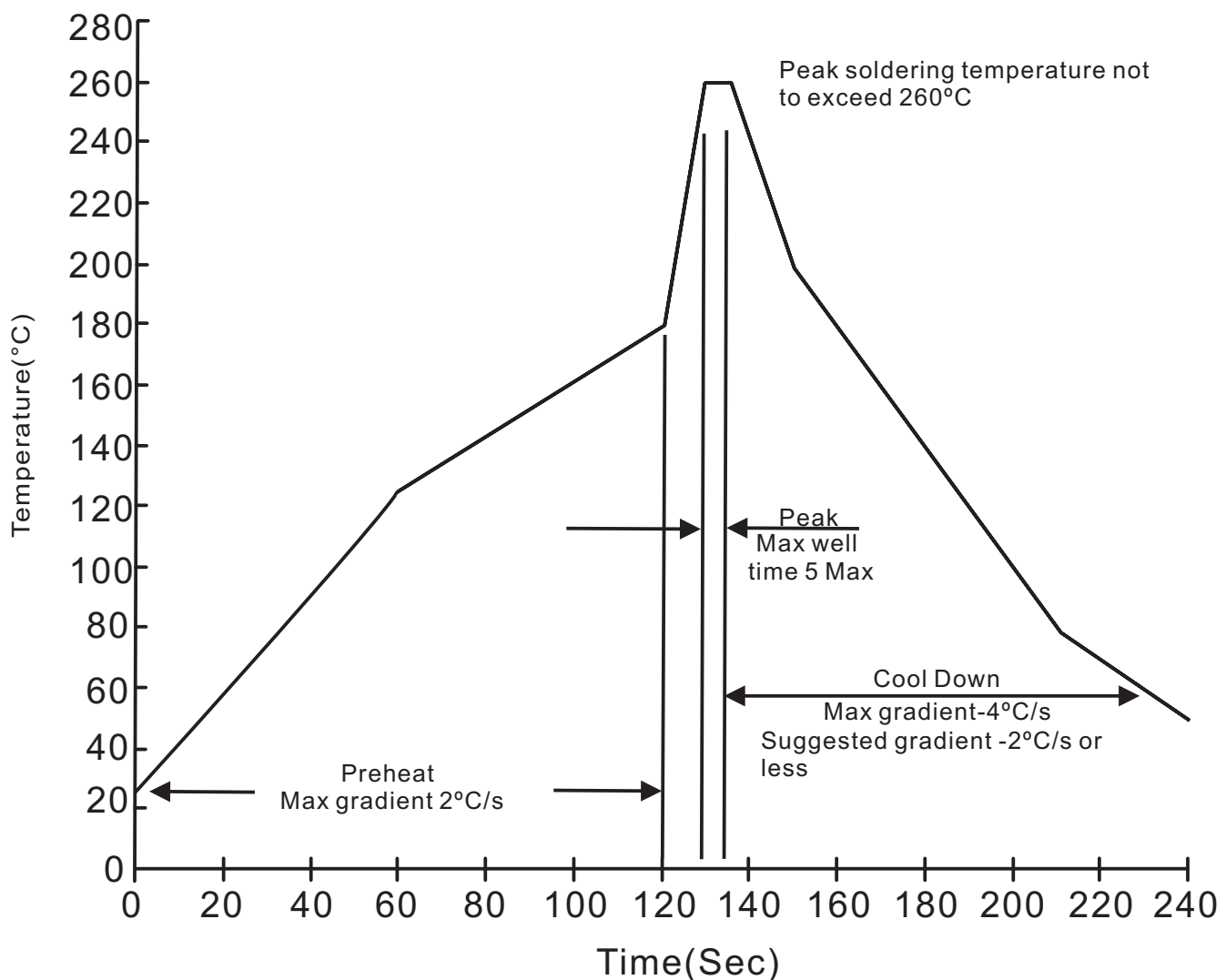
Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code
EF8A05	EF8A05
EF8A10	EF8A10
EF8A20	EF8A20
EF8A40	EF8A40
EF8A60	EF8A60

Tube packing

PACKAGE	TUBE (pcs)	TUBE SIZE (m/m)	BOX (pcs)	INNER BOX (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
TO-220AC	50	525*32*7.5	1000	555*150*40	580*230*175	5,000	15.0

EF8A05 THRU EF8A60**Suggested thermal profiles for soldering processes****1. Lead free temperature profile wave-soldering**

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High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at $260 \pm 5^{\circ}\text{C}$ for $10 \pm 2\text{sec.}$ immerse body into solder $1/16" \pm 1/32"$	MIL-STD-750D METHOD-2031
2. Solderability	at $245 \pm 5^{\circ}\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R = 80\%$ rate at $T_J = 150^{\circ}\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A = 25^{\circ}\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^{\circ}\text{C}$, $I_F = I_O$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A = 121^{\circ}\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to $+125^{\circ}\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	8.3ms single half sine-wave , one surge.	MIL-STD-750D METHOD-4066-2
9. Humidity	at $T_A = 85^{\circ}\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031